TOIREX

XP131A1617SR

ETR1105_001

Power MOSFET

■ GENERAL DESCRIPTION

The XP131A1617SR is an N-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy $\frac{1}{2}$

The small SOP-8 package makes high density mounting possible.

■APPLICATIONS

- ●Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance: Rds(on)= 0.014Ω (Vgs=4.5V)

: Rds(on)=0.019 Ω (Vgs=2.5V)

Ultra High-Speed Switching

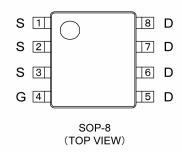
Driving Voltage : 2.5V

N-Channel Power MOSFET

DMOS Structure

Package : SOP-8

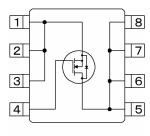
■PIN CONFIGURATION



■PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

■EQUIVALENT CIRCUIT



N-channel MOSFET (1 device built-in)

■ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	20	V
Gate-Source Voltage	Vgss	±12	V
Drain Current (DC)	ld	10	Α
Drain Current (Pulse)	ldp	40	Α
Reverse Drain Current	ldr	10	Α
Channel Power Dissipation *	Pd	2.5	W
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55~150	°C

^{*} When implemented on a glass epoxy PCB

■ELECTRICAL CHARACTERISTICS

DC Characteristics Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=20V, Vgs=0V	-	-	10	μΑ
Gate-Source Leak Current	Igss	Vgs=±12V, Vds=0V	-	-	±1	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	Id=1mA, Vds=10V	0.7	-	1.4	V
Drain-Source On-State Resistance *	Rds(on)	Id=5A, Vgs=4.5V	-	0.010	0.014	Ω
Dialit-Source Oil-State Resistance		Id=5A, Vgs=2.5V	-	0.013	0.019	Ω
Forward Transfer Admittance *	Yfs	Id=5A, Vds=10V	-	32	-	S
Body Drain Diode Forward Voltage	Vf	If=10A, Vgs=0V	-	0.8	1.1	V

^{*} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=10V, Vgs=0V f=1MHz	-	1650	-	pF
Output Capacitance	Coss		ı	1000	ı	pF
Feedback Capacitance	Crss		-	450	-	pF

Switching Characteristics

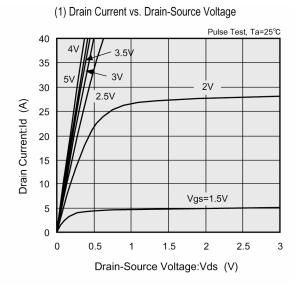
Ta = 25°C

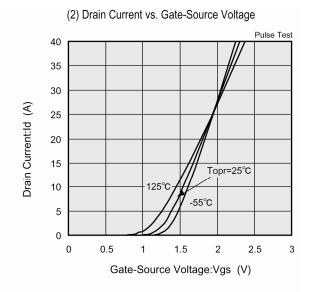
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs=5V, Id=5A Vdd=10V	ı	15	ı	ns
Rise Time	tr		ı	25	ı	ns
Turn-Off Delay Time	td (off)		-	65	-	ns
Fall Time	tf		-	15	-	ns

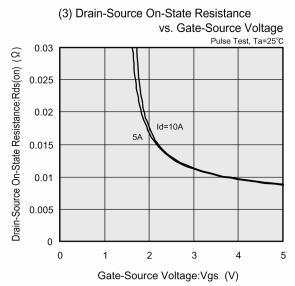
Thermal Characteristics

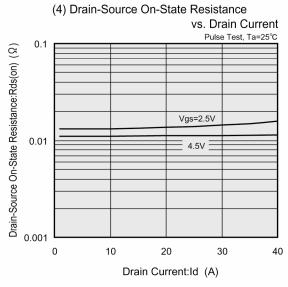
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Aambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

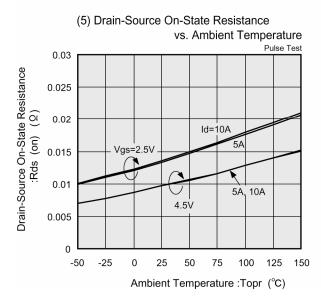
■TYPICAL PERFORMANCE CHARACTERISTICS

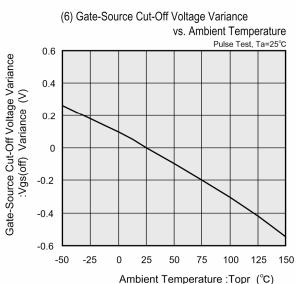




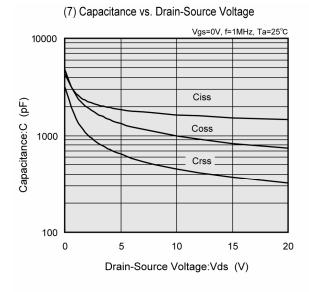


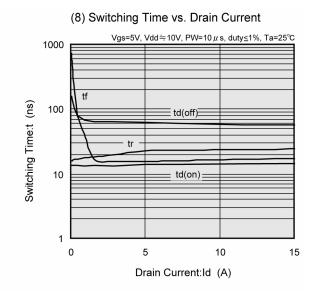


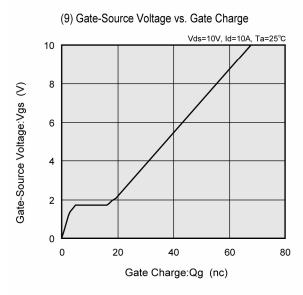


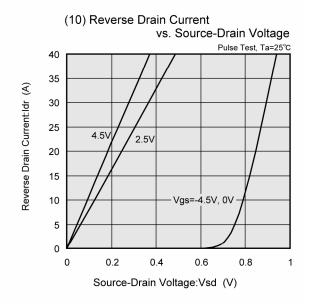


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

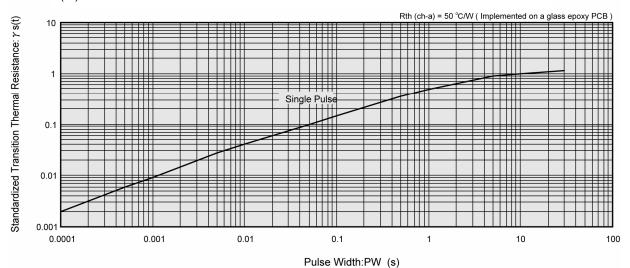












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